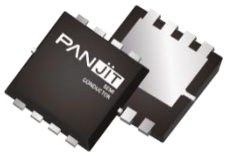
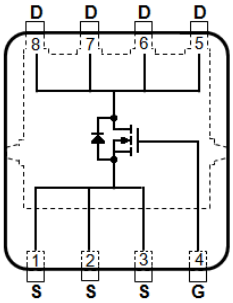
PJQ4464AP

60V N-Channel Enhancement Mode MOSFET

Voltage	60 V	Current	33 A

DFN3333-8L





Features

- $R_{DS(ON)}$, V_{GS}@10V, I_D@16A<17mΩ
- $R_{DS(ON)}$, V_{GS}@4.5V, I_D@8A<20mΩ
- Advanced Trench Process Technology
- High density cell design for ultra low on-resistance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : DFN3333-8L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.03 grams

Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V_{DS}	60	V
Gate-Source Voltage		V_{GS}	±20	
Continuous Drain Current(Note 4)	T_C=25°C	I_D	33	A
	T_C=100°C		21	
Pulsed Drain Current(Note 1)	T_C=25°C	I_{DM}	132	
Power Dissipation	T_C=25°C	P_D	40	W
	T_C=100°C		16	
Continuous Drain Current	T_A=25°C	I_D	7.3	A
	T_A=70°C		5.9	
Power Dissipation	T_A=25°C	P_D	2.0	W
	T_A=70°C		1.3	
Single Pulse Avalanche Energy(Note 6)		E_{AS}	45	mJ
Operating Junction and Storage Temperature Range		T_J,T_{STG}	-55~150	°C
Typical Thermal Resistance(Note 4,5)	Junction to Case	$R_{\theta JC}$	3.1	°C/W
	Junction to Ambient	$R_{\theta JA}$	62.5	

- Limited only By Maximum Junction Temperature

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Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV_{DSS}	V_{GS}=0V, I_D=250uA	60	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	V_{DS}=V_{GS}, I_D=250uA	1	1.7	2.5	
Drain-Source On-State Resistance	$R_{DS(on)}$	V_{GS}=10V, I_D=16A	-	13	17	mΩ
		V_{GS}=4.5V, I_D=8A	-	16	20	
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS}=60V, V_{GS}=0V	-	-	1	uA
Gate-Source Leakage Current	I_{GSS}	V_{GS}=±20V, V_{DS}=0V	-	-	±100	nA
Dynamic(Note 5)						
Total Gate Charge	Q_g	V_{DS}=30V, I_D=10A, V_{GS}=4.5V(Note 1,2)	-	13.5	-	nC
Gate-Source Charge	Q_{gs}		-	4.8	-	
Gate-Drain Charge	Q_{gd}		-	4.9	-	
Input Capacitance	Ciss	V_{DS}=25V, V_{GS}=0V, f=1MHZ	-	1574	-	pF
Output Capacitance	Coss		-	118	-	
Reverse Transfer Capacitance	Crss		-	77	-	
Turn-On Delay Time	$td_{(on)}$	V_{DD}=15V, I_D=1A, V_{GS}=10V, R_G=6Ω (Note 1,2)	-	11	-	ns
Turn-On Rise Time	t_r		-	11	-	
Turn-Off Delay Time	$td_{(off)}$		-	35	-	
Turn-Off Fall Time	t_f		-	8.1	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I_S	---	-	-	33	A
Reverse Recovery Time	V_{SD}	I_S=1A, V_{GS}=0V	-	0.68	1	V

NOTES :

1. Pulse width≤300us, Duty cycle≤2%.
2. Essentially independent of operating temperature typical characteristics.
3. Repetitive rating, pulse width limited by junction temperature $T_{J(MAX)}$=150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
4. The maximum current rating is package limited.
5. $R_{\Theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch^2 with 2oz.square pad of copper.
6. The test condition is L=0.1mH, I_{AS}=30A, V_{DD}=25V, V_{GS}=10V, Starting T_J=25°C.
7. Guaranteed by design, not subject to production testing.

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TYPICAL CHARACTERISTIC CURVES

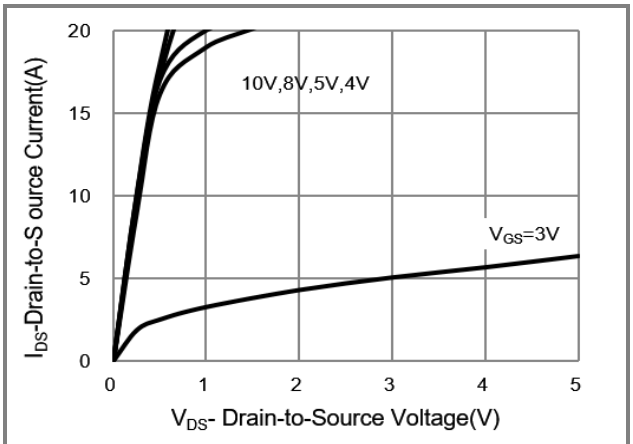

Fig.1 On-Region Characteristics

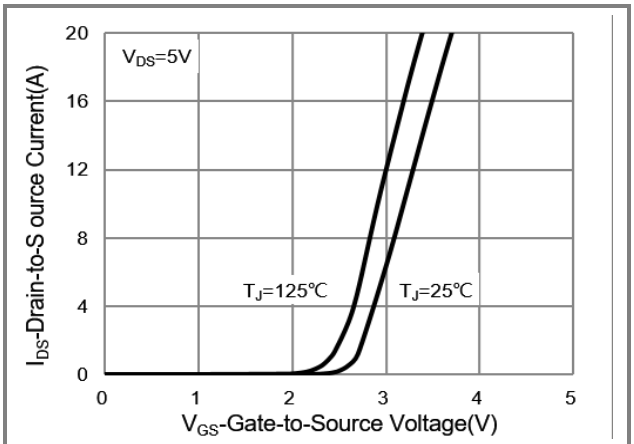

Fig.2 Transfer Characteristics

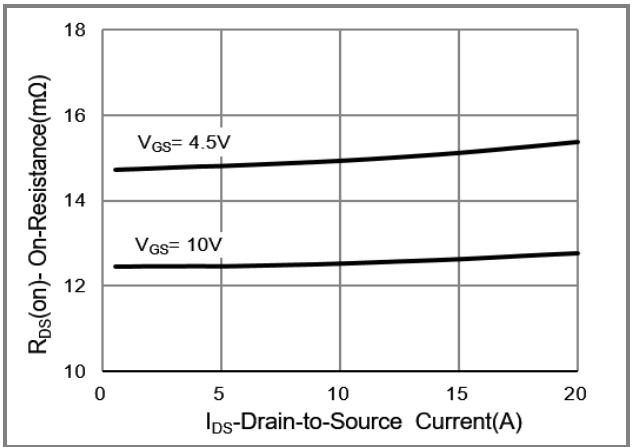

Fig.3 On-Resistance vs. Drain Current

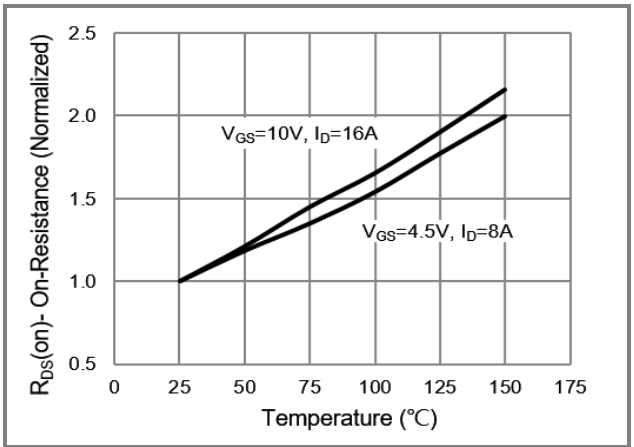

Fig.4 On-Resistance vs. Junction temperature

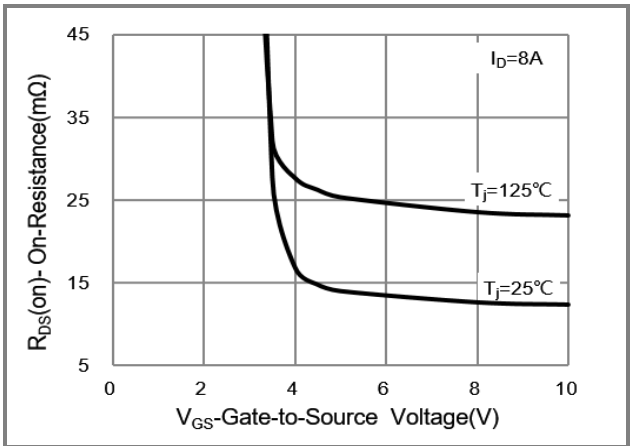

Fig.5 On-Resistance Variation with V_{GS}

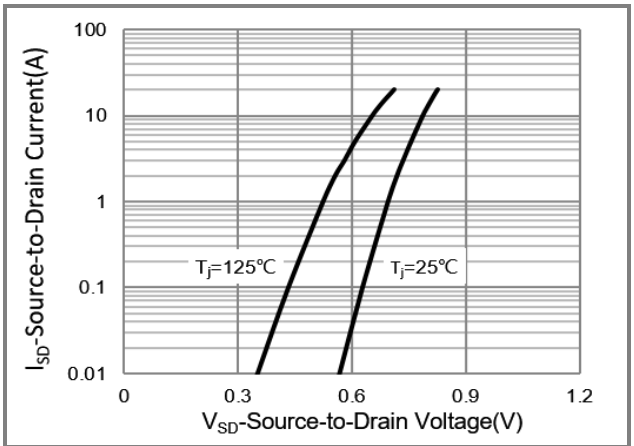

Fig.6 Source-Drain Diode Forward Voltage

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TYPICAL CHARACTERISTIC CURVES

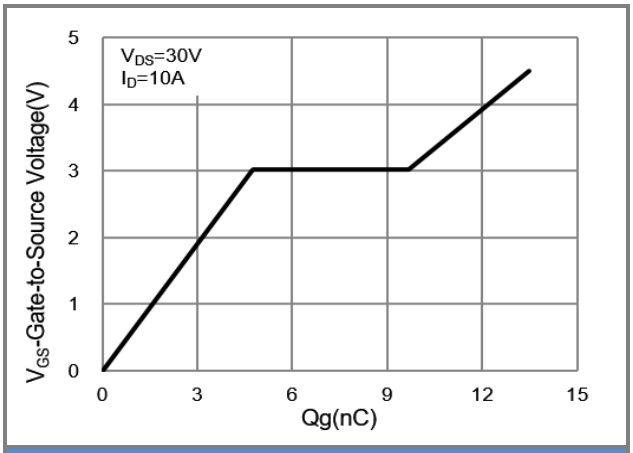

Fig.7 Gate-Charge Characteristics

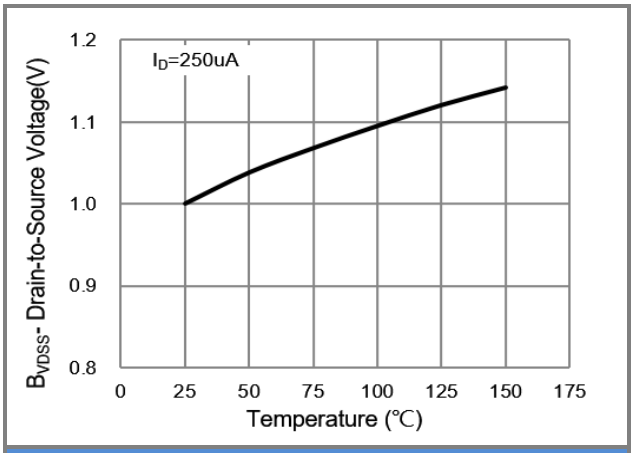

Fig.8 Breakdown Voltage Variation vs. Temperature

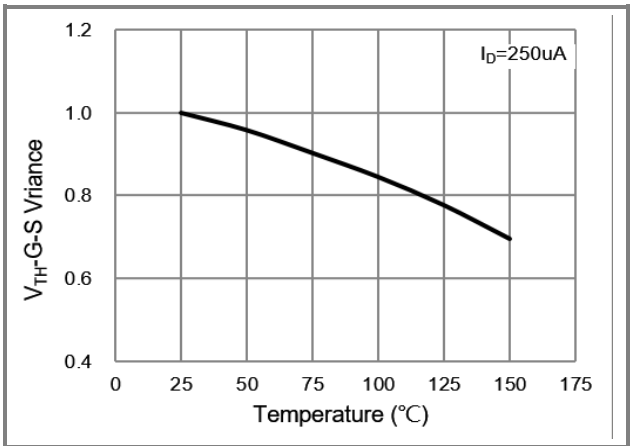

Fig.9 Threshold Voltage Variation with Temperature

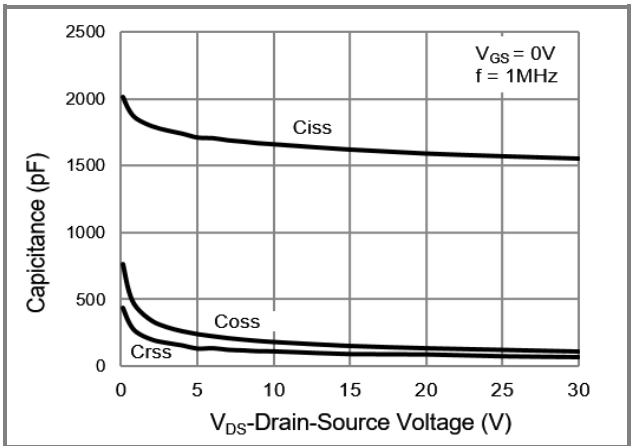

Fig.10 Capacitance vs. Drain-Source Voltage

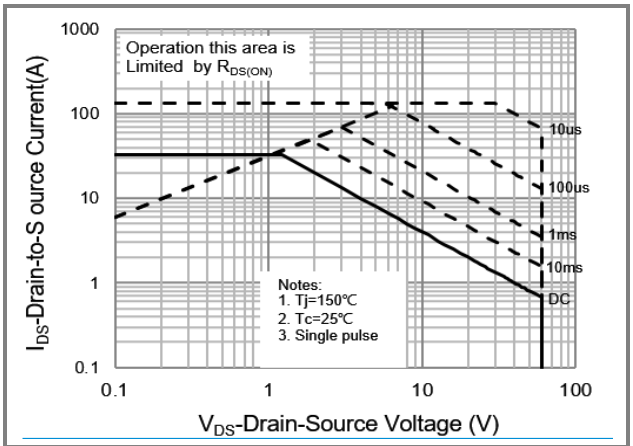

Fig.11 Maximum Safe Operating Area

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TYPICAL CHARACTERISTIC CURVES

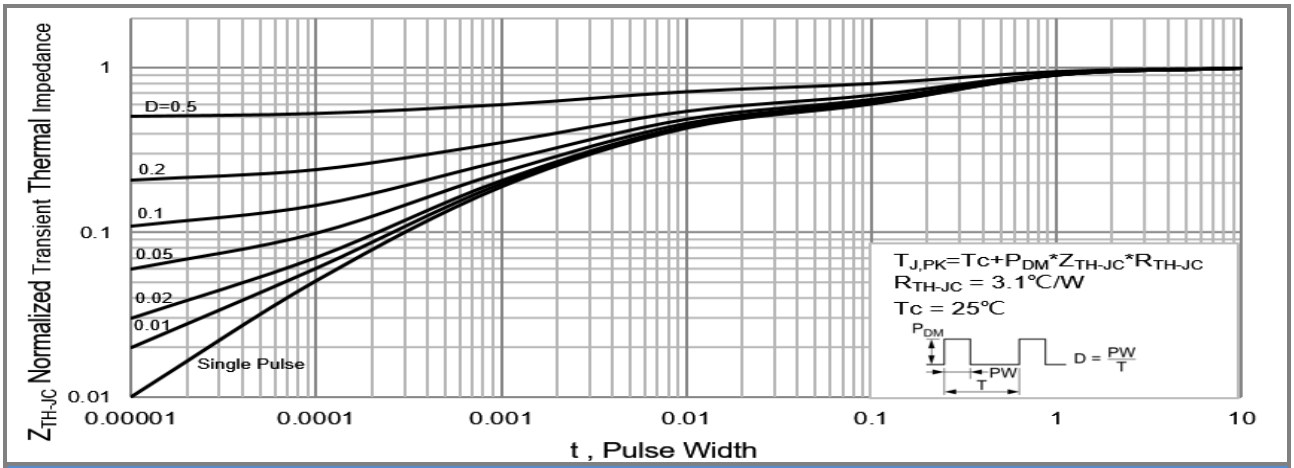


Fig.12 Normalized Transient Thermal Impedance vs. Pulse Width

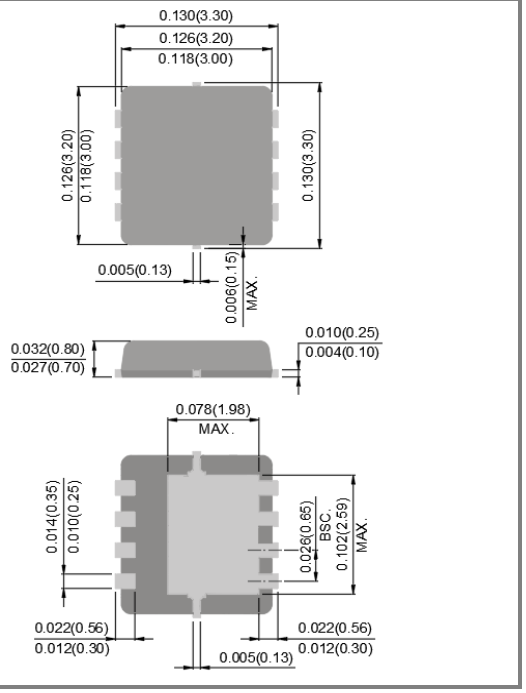
PJQ4464AP

Part No. Packing Code Version

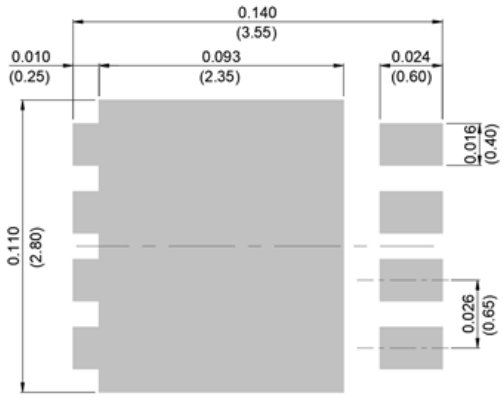
Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJQ4464AP_R2_00001	DFN3333-8L	5K pcs / 13” reel	4464	Halogen free RoHS compliant

Packaging Information & Mounting Pad Layout

DFN3333-8L Dimension — Unit: inch(mm)



DFN3333-8L Pad Layout — Unit: inch(mm)



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